## 九十一年度台灣大學電資學院電機系電子學(一)期中考題

## \*本試題共有三張,請同學檢查確認\*

- 1. Consider the circuit shown in fig. 1 for the case R=10 kΩ. The power supply V<sup>+</sup> has a dc value of 10 V on which is superimposed a 60-Hz sinusoid of 1-V peak amplitude. (this "signal" component of the power supply voltage is an imperfection in the power-supply design. It is known as the power-supply ripple) Calculate both the dc voltage of the diode and the amplitude of the sine-wave signal appearing across it. Assume the diode to have a 0.7-V drop at 1-mA current and n=2. (6%)
- 2. A shunt regulator utilizes a zener diode whose voltage is 5.1 V at a current of 50mA and whose incremental resistance is  $7\Omega$ . The diode is fed from a supply of 15-V nominal voltage through a 200- $\Omega$  resistor. What is the output voltage at no load? Find the line regulation and the load regulation. (7%)
- 3. voltage doubler:

Consider the transition response of the voltage doubler shown in Fig.2(a). The input voltage  $Vi(t)=Vpsin(\omega t)$  is shown in Fig.2(b). Assuming no charge in C1 and C2 when t=0.

- (a) When  $0 \le t \le T/4$ , D1 is on or off? D2 is on or off? (2%)
- (b) What are the voltages across C1 and C2 when t=T/4? (1%)
- (c) When T/4 < t < 5T/12, D1 is on or off? D2 is on or off? (2%)
- (d) When 5T/12 < t < 3T/4, D1 is on or off? D2 is on or off? (2%)
- (e) What are the voltages across C1 and C2 when t=3T/4? (1%)
- (f) When 3T/4 < t < 11T/12, D1 is on or off? D2 is on or off? (2%)
- (g) When 11T/12<t<5T/4, D1 is on or off? D2 is on or off? (2%)
- (h) What is the voltage across C2 when t=5T/4? (3%)
- (i) What is the voltage across C2 when t=9T/4? (3%)
- (j) What is the voltage across C2 when  $t \rightarrow \infty$ ? (2%)

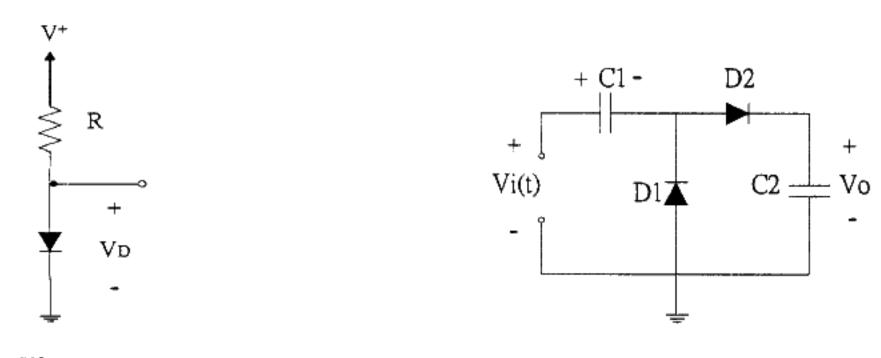


Fig. 1

Fig. 2(a)

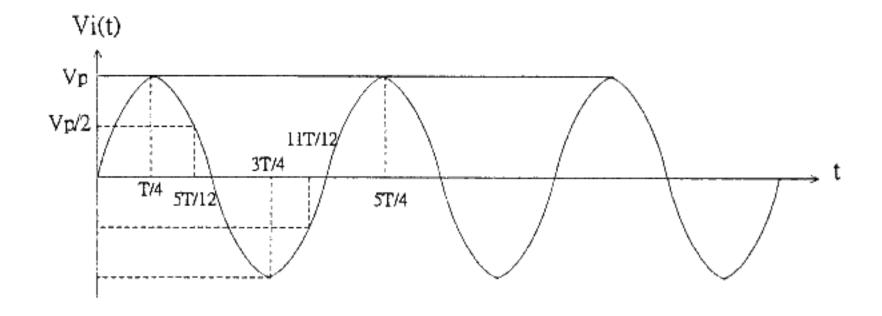


Fig. 2(b)

An OPAMP circuit is shown in Fig. 3, the OPAMP is an ideal OPAMP. Find vo and I<sub>2</sub>.
(18%)

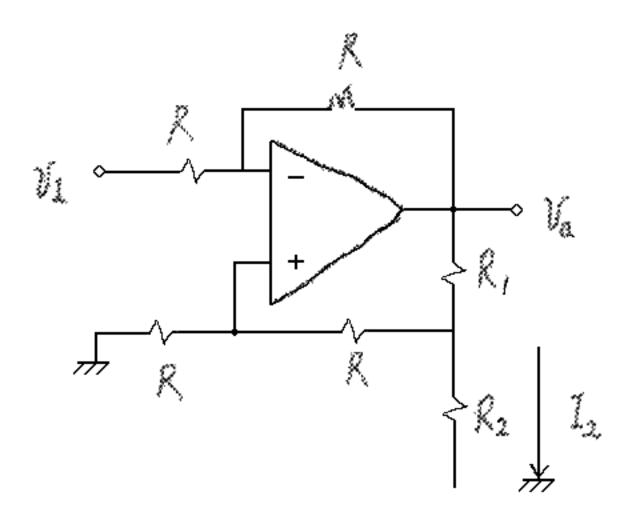


Fig. 3

- 5. For an OPAMP inverting amplifier, the slew rate is SR and the maximum amplitude of the output voltage is  $V_{\rm OMAX}$ . Find the full-power bandwidth. (8%)
- 6. The circuit shown in Fig. 4 uses four diodes.  $V_T = 25 \text{mV}$ . These diodes have identical junction ideality factors, n = 2. Their saturation currents have the following relation.  $I_{S1}: I_{S2}: I_{S3}: I_{S4} = 1:2:4:8$ . Find V. (7%)

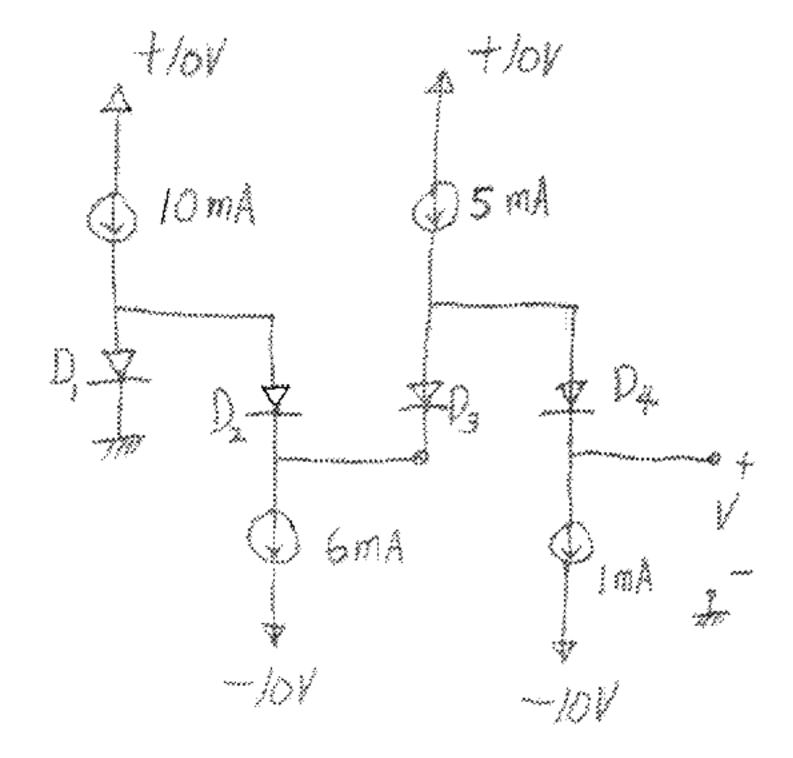
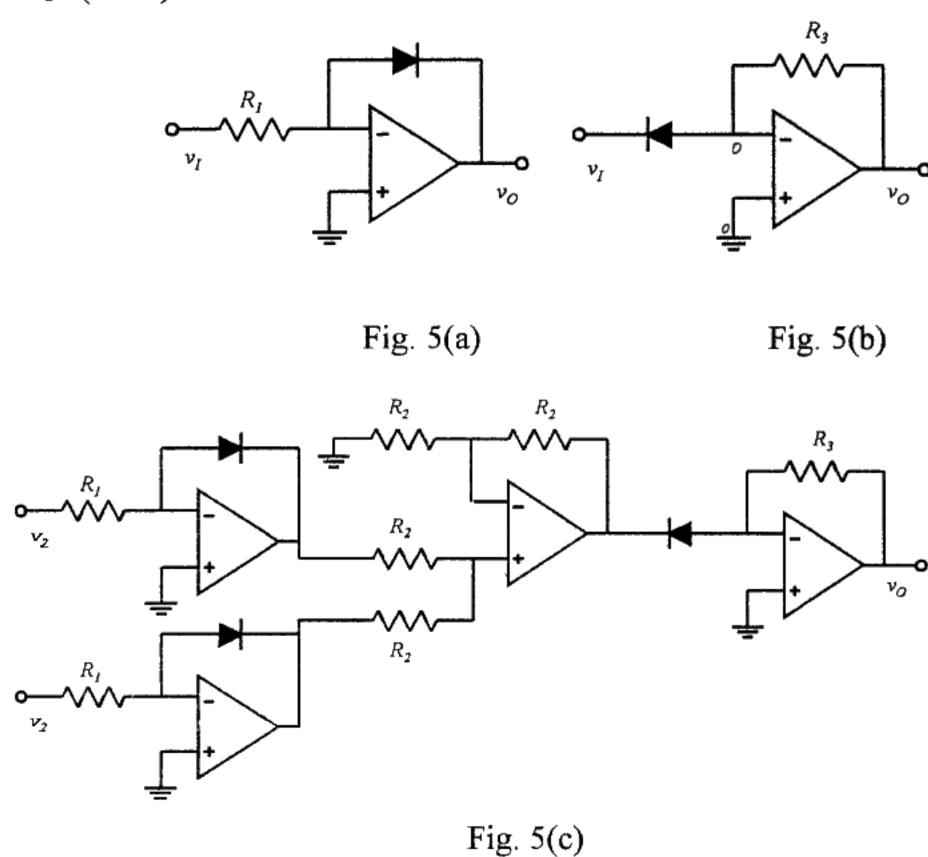


Fig. 4

- 7. Assuming that the op amp is ideal and the diode current can expressed as  $I_D = I_S e^{V_D/V_T}$ , analyze the following circuits:
- (1) Derive the expression for the output voltage  $v_0$  in Fig. 5(a) for a positive  $v_I$ . (5 %)
- (2) Derive the expression for the output voltage  $v_0$  in Fig. 5(b) for a negative  $v_I$ . (5 %)
- (3) With the expressions derived above, what is the output voltage  $v_0$  in Fig. 5(c) for positive  $v_1$  and  $v_2$ ? (10 %)



8. Consider the circuit in Fig. 6 for  $R_I$ =10K $\Omega$ ,  $R_2$ =10K $\Omega$ ,  $R_3$ =1K $\Omega$ ,  $I_{EE}$ =11mA,  $\beta(npn)$ =50 and  $\beta(pnp)$ =10. Assuming the transistors are in forward active region and the forward bias at emitter-base junction is 0.7V for both npn and pnp, find the voltage  $V_A$  (4%),  $V_B$  (3%),  $V_C$  (3%) and  $V_D$  (4%).

(Hint: collector current of npn = base current of pnp + current of  $R_I$ )

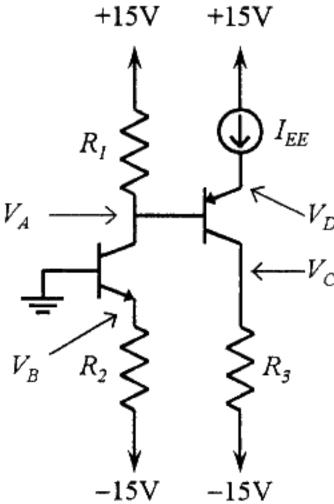


Fig. 6